

### Product Summary

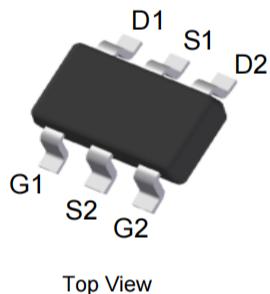
- $V_{DS} = 30V, I_D = 4A$
- $R_{DS(ON)} < 75m\Omega @ V_{GS}=4.5V$
- $R_{DS(ON)} < 45m\Omega @ V_{GS}=10V$

### Application

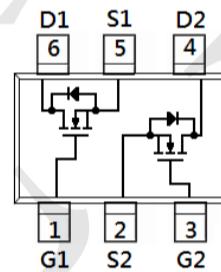
- Notebook
- Load Switch
- Networking
- Hand-held Instruments

### Package and Pin Configuration

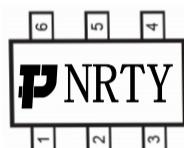
SOT23-6



Circuit diagram



Marking:



### Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	4	A
Drain Current-Pulsed <sup>(Note 1)</sup>	$I_{DM}$	20	A
Maximum Power Dissipation	$P_D$	1.2	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup>	$R_{\theta JA}$	104	°C/W
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**TPM30V4NBS6**

**30V Dual N-Channel Enhancement Mode MOSFET**

[www.sot23.com.tw](http://www.sot23.com.tw)

**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	30			V
Zero Gate Voltage Drain Current	$\text{I}_{\text{DSS}}$	$\text{V}_{\text{DS}}=30\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage Current	$\text{I}_{\text{GSS}}$	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	1.2	1.5	2.2	V
Drain-Source On-State Resistance	$\text{R}_{\text{DS(ON)}}$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=3\text{A}$	-	35	45	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=2\text{A}$	-	60	75	$\text{m}\Omega$
Forward Transconductance	$\text{g}_{\text{FS}}$	$\text{V}_{\text{DS}}=5\text{V}, \text{I}_D=3.5\text{A}$	-	12	-	S
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$\text{C}_{\text{iss}}$	$\text{V}_{\text{DS}}=15\text{V}, \text{V}_{\text{GS}}=0\text{V},$ $F=1.0\text{MHz}$	-	170	-	PF
Output Capacitance	$\text{C}_{\text{oss}}$		-	35	-	PF
Reverse Transfer Capacitance	$\text{C}_{\text{rss}}$		-	23	-	PF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{\text{d(on)}}$	$\text{V}_{\text{DS}}=15\text{V}, \text{R}_L=4.2\Omega$ $\text{V}_{\text{GS}}=10\text{V}, \text{R}_{\text{GEN}}=3\Omega$	-	4.5	-	nS
Turn-on Rise Time	$t_r$		-	1.5	-	nS
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	18.5	-	nS
Turn-Off Fall Time	$t_f$		-	15.5	-	nS
Total Gate Charge	$\text{Q}_g$	$\text{V}_{\text{DS}}=15\text{V}, \text{I}_D=3.5\text{A},$ $\text{V}_{\text{GS}}=10\text{V}$	-	4.0	-	nC
Gate-Source Charge	$\text{Q}_{\text{gs}}$		-	0.75	-	nC
Gate-Drain Charge	$\text{Q}_{\text{gd}}$		-	0.65	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$\text{V}_{\text{SD}}$	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_s=3.5\text{A}$	-	0.8	1.2	V
Diode Forward Current <sup>(Note 2)</sup>	$\text{I}_s$		-	-	3.5	A

### Typical Electrical and Thermal Characteristics

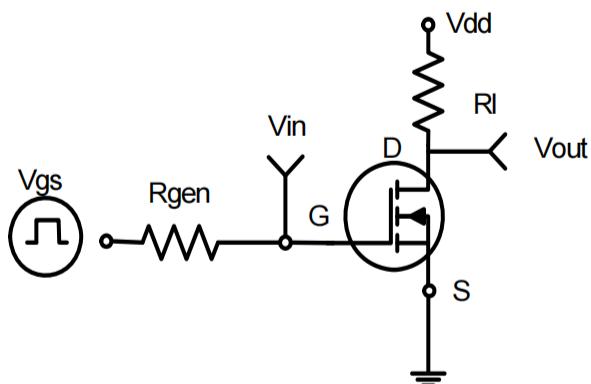


Figure 1:Switching Test Circuit

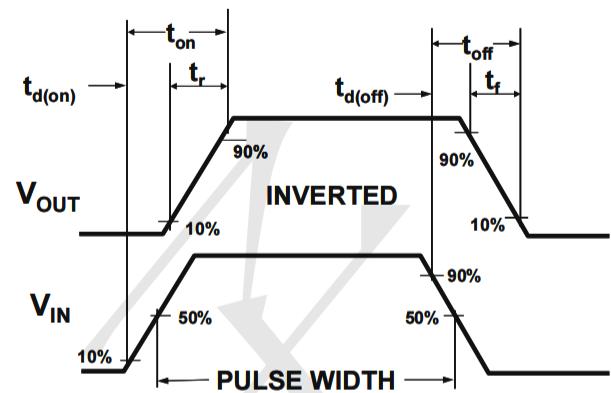
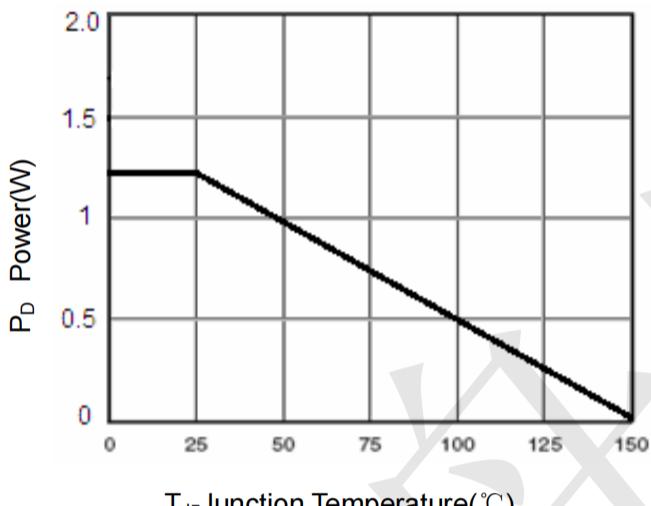
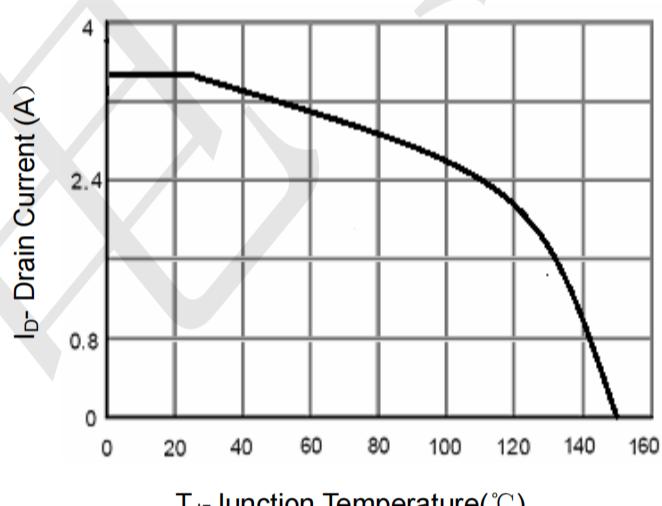


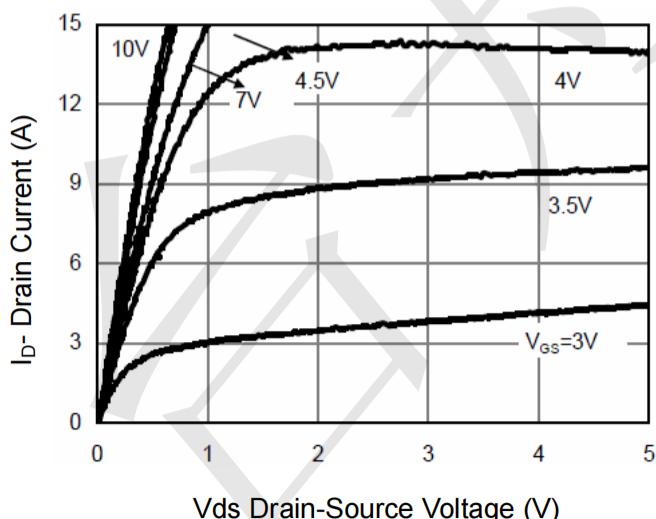
Figure 2:Switching Waveforms



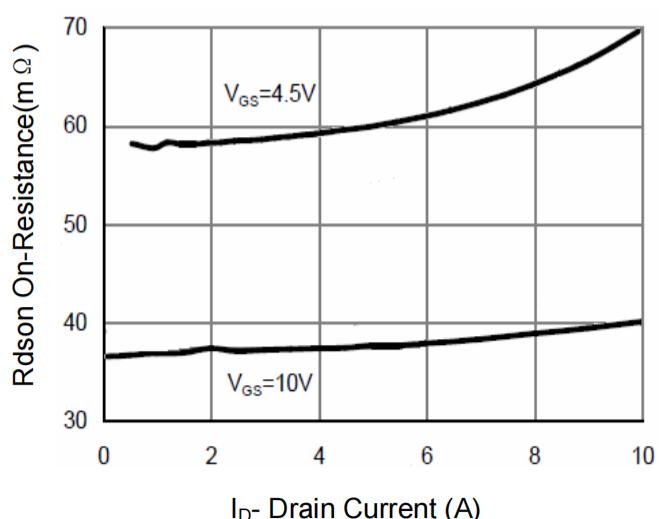
T<sub>J</sub>-Junction Temperature(°C)  
Figure 3 Power Dissipation



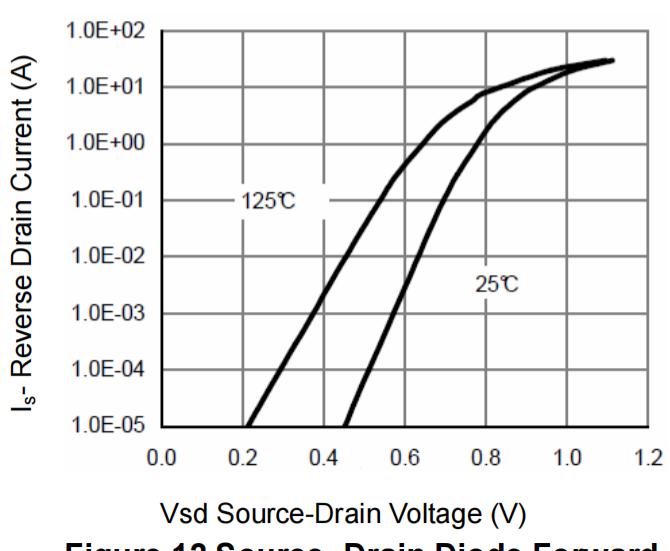
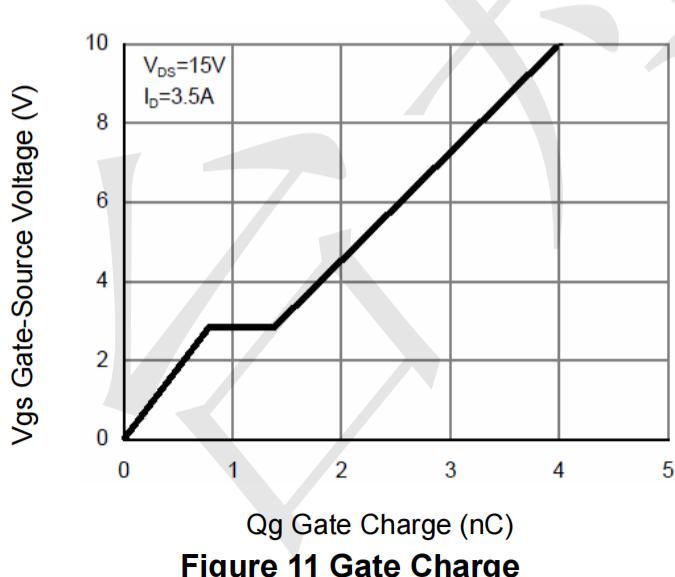
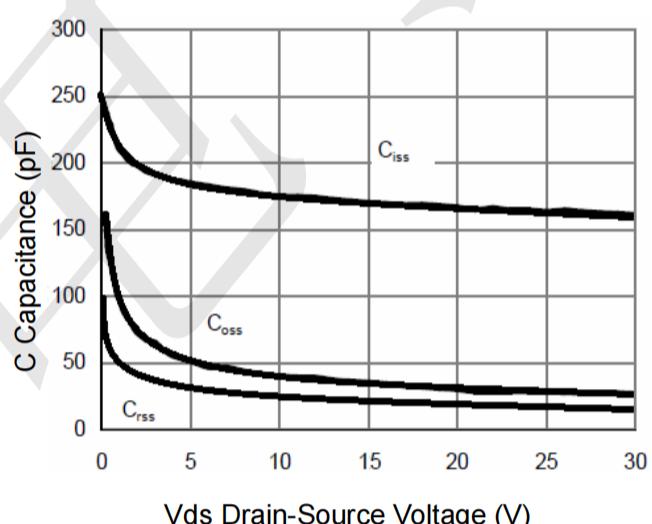
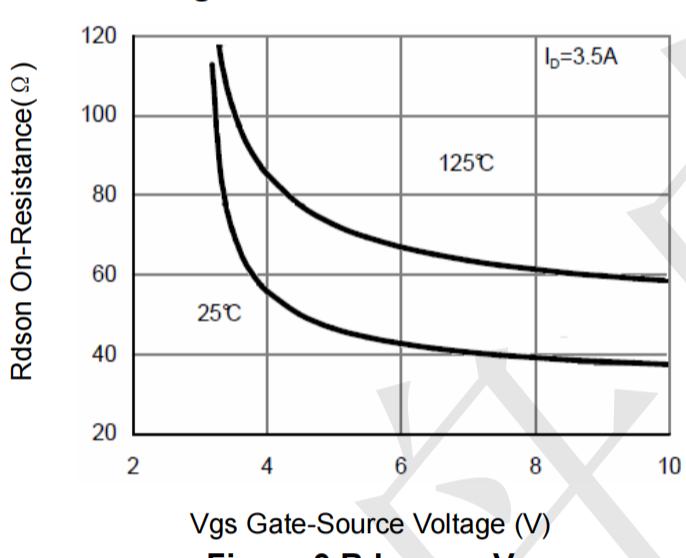
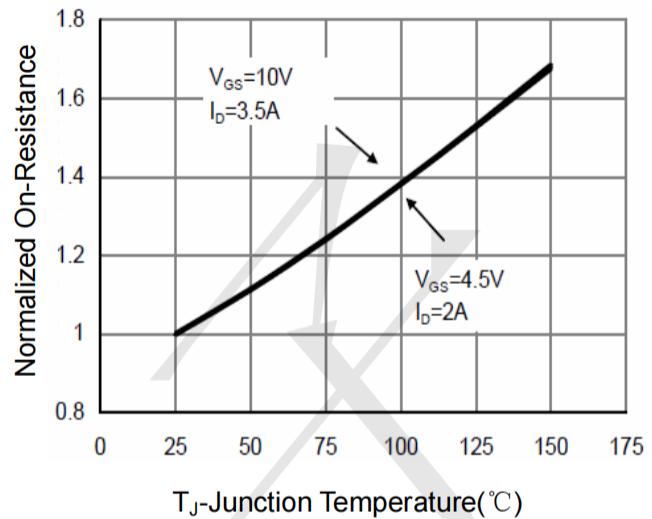
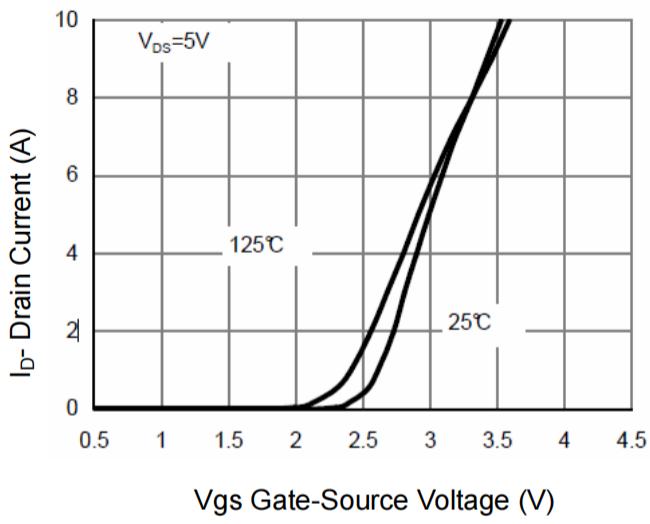
T<sub>J</sub>-Junction Temperature(°C)  
Figure 4 Drain Current

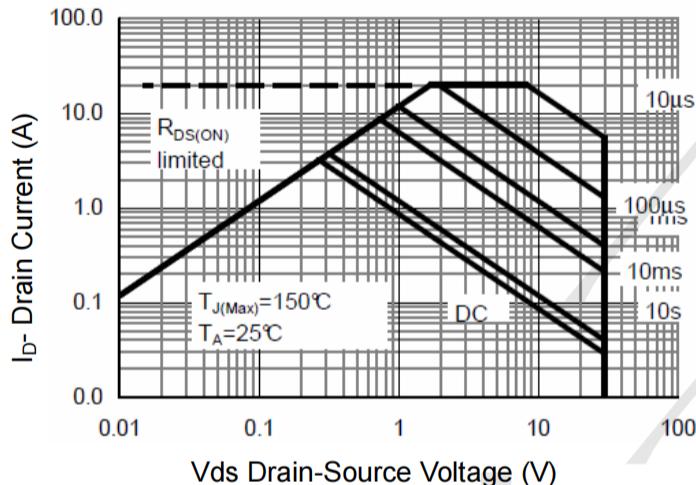


V<sub>Ds</sub>- Drain-Source Voltage (V)  
Figure 5 Output Characteristics

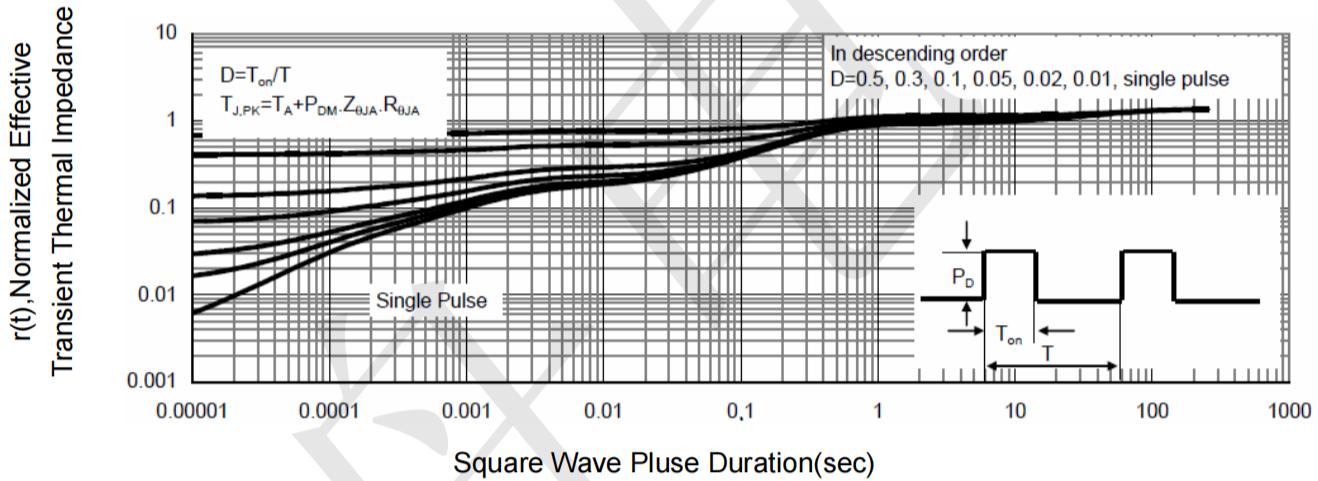


I<sub>D</sub>- Drain Current (A)  
Figure 6 Drain-Source On-Resistance



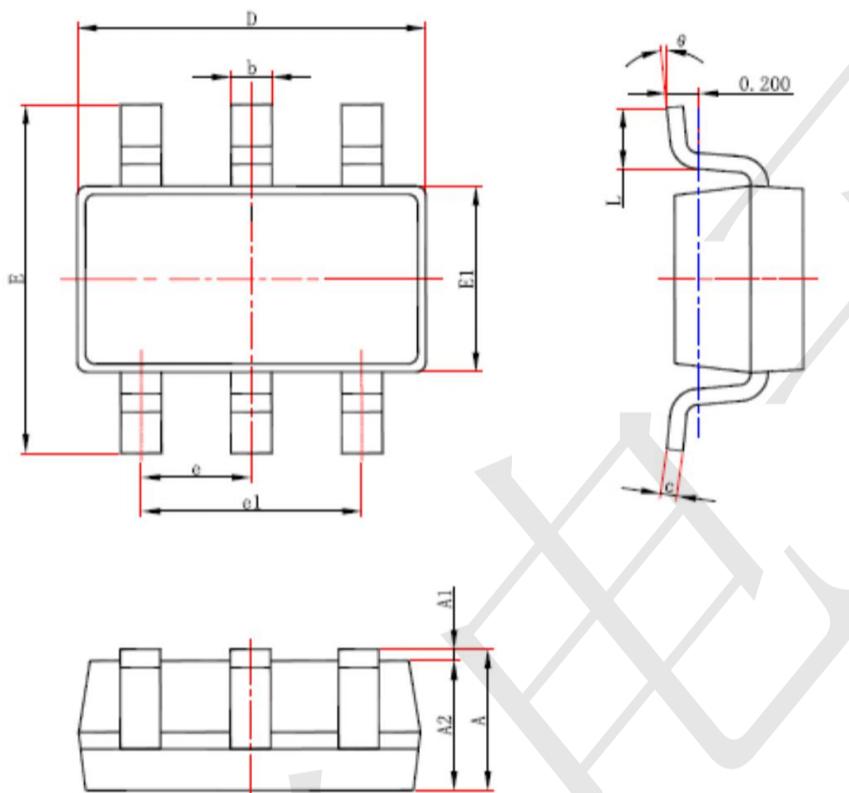


**Figure 13 Safe Operation Area**



**Figure 14 Normalized Maximum Transient Thermal Impedance**

**SOT23-6 Package Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°